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Mechanical design



MODEL NO : ET047HD01-T

MODEL VERSION: 01

SPEC VERSION : 1.0

ISSUED DATE: 2022-07-07

☐ Preliminary Specification

☒ Final Product Specification

Customer : _____

Approved by	Notes

Youri Confirmation

Prepared by	Reviewed by	Approved by
John	Johnny	Wang

1. Introduction

1.1 Scope of application

LCD specification: Dots 720xRGBx1280.

As to basic specification of the driver IC, refer to the IC (JD936DA-H3) specification and data book.

All material & processing of the LCD module should be Lead Free.

1.2 TFT features:

Structure: TFT PANNEL+IC +FPC1+BL;

IPS Type LCD

720dot-segment and 1280 dot-common outputs;

16.7M Color can be selected by software;

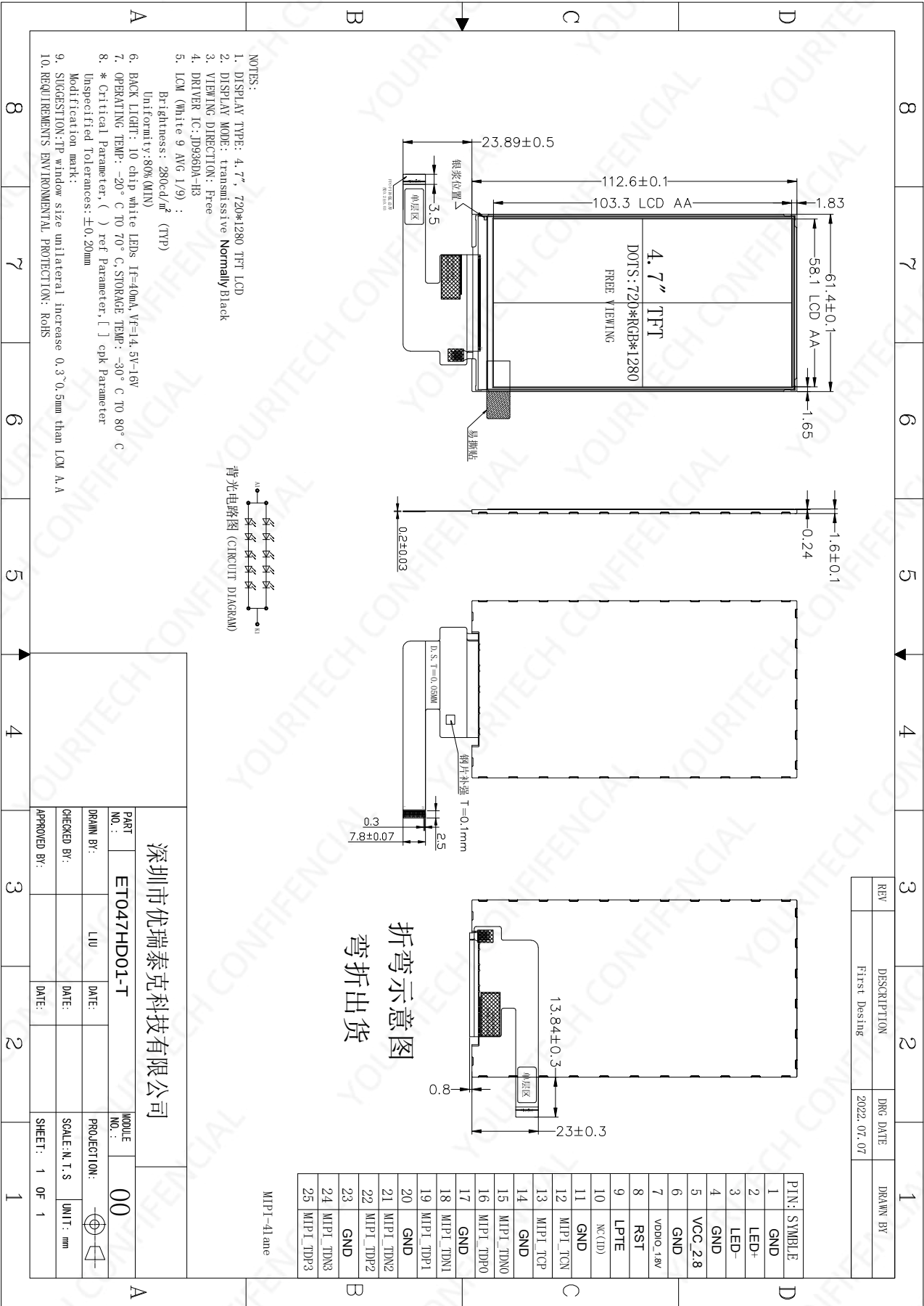
White LED back light;

4 Lane MIPI Interface can be selected by software;

1.3 Applications:

2. LCM General specification

ITEM	Standard value	Unit
LCD Type	Normally Black	--
Drive element	TFT active matrix	--
Number of pixels	720*3RGB(H)X1280(V)	Dots
Pixel arrangement	RGB stripe	--
Pixel Pitch (W*H)	0.0807(W) × 0.0807(H)	mm
Active area	58.10(W) × 103.30(H)	mm
Viewing direction	ALL O'CLOCK	--
TFT Driver IC	JD936DA-H3	--
TFT interface	4 lane Interface	--
Module Size(W*H*T)	61.40(W) × 112.60(H) × 1.6(T)	mm
Approx. Weight	TBD	g
Touch structure	--	--
Touch Driver IC	--	--
Touch Interface	--	--



3. Absolute Maximum Rating

Characteristics	Symbol	Min.	Max.	Unit
LCM Operating Temperature	T _{OPR}	-20	+70	°C
LCM Storage Temperature	T _{STG}	-30	+80	°C
Humidity	RH	--	90	%

4. Electrical Characteristics

4.1 TFT DC Characteristics

Characteristics	Symbol	Min.	Typ.	Max.	Unit
Supply Voltage for I/O	VDDIO	1.65	1.8	3.3	V
Supply Voltage for(DC/DC)	VDD	2.5	2.8	3.6	V
Supply Voltage for(DC/DC)	AVDD	--	--	--	V
Supply Voltage for(DC/DC)	AVEE	--	--	--	V

4.2 Back-Light Unit Characteristics

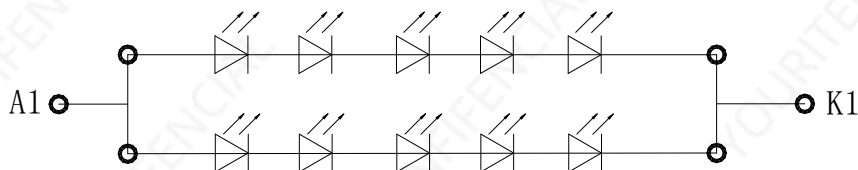
The back-light system is an edge-lighting type with 10 white LEDs. The characteristics of the back-light are shown in the following tables.

Characteristics	Symbol	Min.	Type	Max.	Unit	Notes
Forward Voltage	V _F	14.5	--	16	V	--
Forward current	I _F	--	40	--	mA	--
Luminance(With LCD)	L _v	--	280	--	cd/m ²	--
LED life time	N/A	--	30,000	--	Hr	Note 1

Note:

- (1) The “LED life time” is defined as the module brightness decrease to 50% of original brightness at I_L=20mA/LED. The LED life time could be decreased if operating I_L is larger than 25mA/LED.

Backlight circuit diagram shown in below:



5. Module Function Description

Pin No.	Symbol	Functional	Notes
1	GND	Power Ground	
2	LEDA	Power supply for backlight anode input terminal.	
3	LEDK	Power supply for backlight cathode input terminal.	
4	GND	Power Ground	
5	VCC 2.8V	Power supply 2.5-3.6V	
6	GND	Power Ground	
7	VDDIO 1.8V	Power supply 1.65-3.3V	
8	RST	Reset signal input terminal. Active at 'L'.	
9	LPTE	Tearing effect signal is used to synchronize MCU to frame memory	
10	NC(ID)	NC	
11	GND	Power Ground	
12	TCN	MIPI-DSI CLOCK differential signal input pins	
13	TCP	MIPI-DSI CLOCK differential signal input pins	
14	GND	Power Ground	
15	TDN0	MIPI-DSI Data differential signal input pins	
16	TDP0	MIPI-DSI Data differential signal input pins	
17	GND	Power Ground	
18	TDN1	MIPI-DSI Data differential signal input pins	
19	TDP1	MIPI-DSI Data differential signal input pins	
20	GND	Power Ground	
21	TDN2	MIPI-DSI Data differential signal input pins	
22	TDP2	MIPI-DSI Data differential signal input pins	
23	GND	Power Ground	
24	TDN3	MIPI-DSI Data differential signal input pins	
25	TDP3	MIPI-DSI Data differential signal input pins	

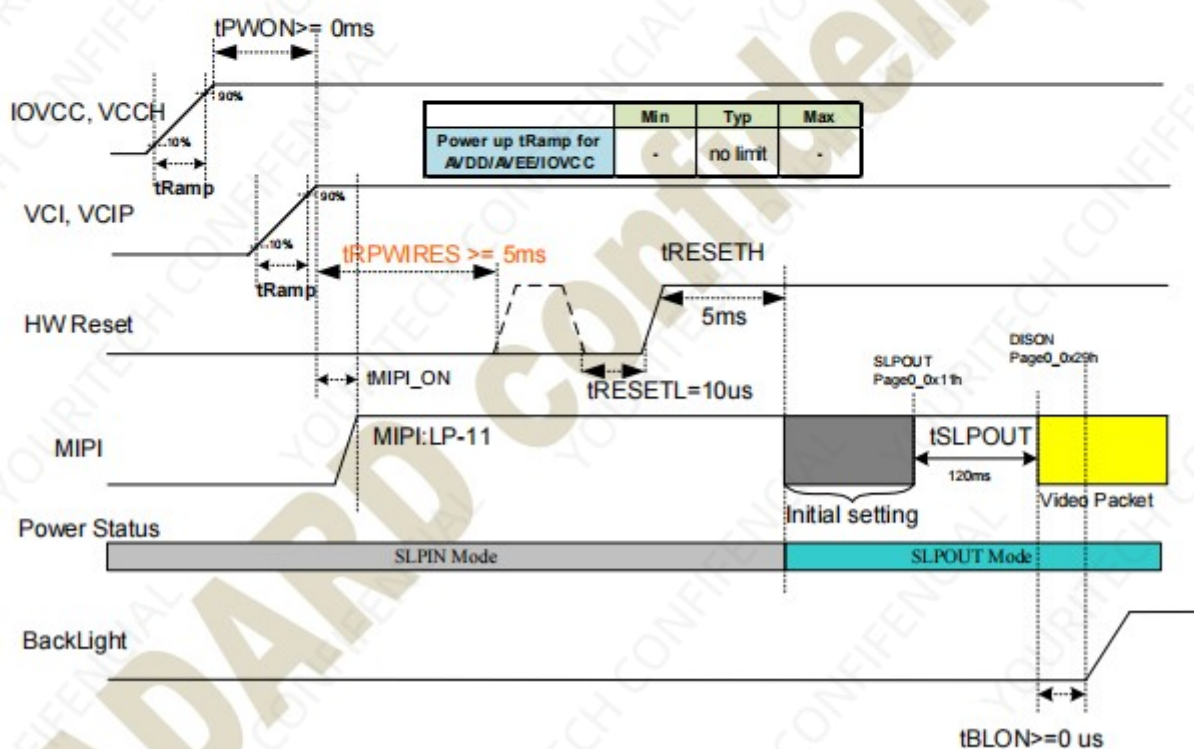
6. Timing Characteristics

Symbol	Min	Typ	Max	Unit	Remark
tRamp	-	no limit	-	us	
tPWON	0	-	-	ms	
tON1	0	-	-	ms	
tMIPI-ON	0	-	tRPWIREs	ms	
tRPWIREs	5	-	-	ms	
tRESETL	10	-	-	us	
tRESETH	5	-	-	ms	
tSLPOUT	120	-	-	ms	
tBLON	0	-	-	ms	

BOOSTM[1:0]=10 (Internal DC/DC power mode : Charge Pump, FP7721)

VCCD=IOVCC=VCCH=1.65V ~ 3.6V, VCI=VCIP=2.5V ~ 4.8V.

Power on:



High-Speed Data-Clock Timing

This section specifies the required timings on the high-speed signaling interface independent of the electrical characteristics of the signal. The PHY is a source synchronous interface in the Forward direction. In either the Forward or Reverse signaling modes there shall be only one clock source. In the Reverse direction, Clock is sent in the Forward direction and one of four possible edges is used to launch the data.

The Master side of the Link shall send a differential clock signal to the Slave side to be used for data sampling. This signal shall be a DDR (half-rate) clock and shall have one transition per data bit time. All timing relationships required for correct data sampling are defined relative to the clock transitions. Therefore, implementations may use frequency spreading modulation on the clock to reduce EMI.

The DDR clock signal shall maintain a quadrature phase relationship to the data signal. Data shall be sampled on both the rising and falling edges of the Clock signal. The term "rising edge" means "rising edge of the differential signal, i.e. CLKP – CLKN, and similarly for "falling edge". Therefore, the period of the Clock signal shall be the sum of two successive instantaneous data bit times. This relationship is shown in Figure 13.5.

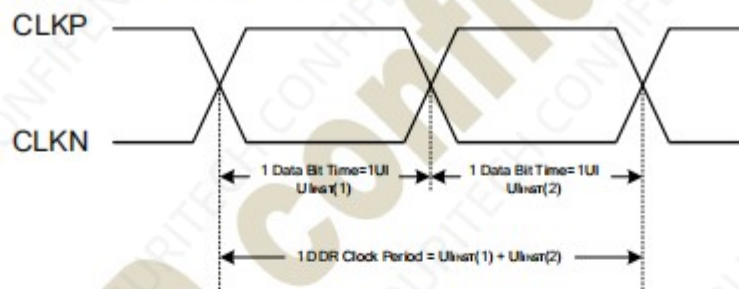


Figure 11.5: DDR Clock Definition

The same clock source is used to generate the DDR Clock and launch the serial data. Since the Clock and Data signals propagate together over a channel of specified skew, the Clock may be used directly to sample the Data lines in the receiver. Such a system can accommodate large instantaneous variations in UI.

The allowed instantaneous UI variation can cause large, instantaneous data rate variations. Therefore, devices shall either accommodate these instantaneous variations with appropriate FIFO logic outside of the PHY or provide an accurate clock source to the Lane Module to eliminate these instantaneous variations.

The UIINST specifications for the Clock signal are summarized in following Table.

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
UI instantaneous	UI _{INST}	-	-	12.5	ns	(1), (2), (3), (4), (5), (6)

Note: (1) This value corresponds to a minimum 80 Mbps data rate.

(2) The minimum UI shall not be violated for any single bit period, i.e., any DDR half cycle within a data burst.

(3) Maximum total bit rate is 850Mbps of 1 data lane 24-bit data format/ 630Mbps of 1 data lane 18-bit data format/ 560Mbps of 1 data lane 16-bit data format.

(4) Maximum total bit rate is 1.7Gbps of 2 data lanes 24-bit data format/ 1.27Gbps of 2 data lane 18-bit data format/ 1.13Gbps of 2 data lane 16-bit data format.

(5) Maximum total bit rate is 2Gbps of 3 data lanes 24-bit data format/ 1.5Gbps of 3 data lane 18-bit data format/ 1.33Gbps of 3 data lane 16-bit data format.

(6) Maximum total bit rate is 2Gbps of 4 data lanes 24-bit data format/ 1.5Gbps of 4 data lane 18-bit data format/ 1.33Gbps of 4 data lane 16-bit data format.

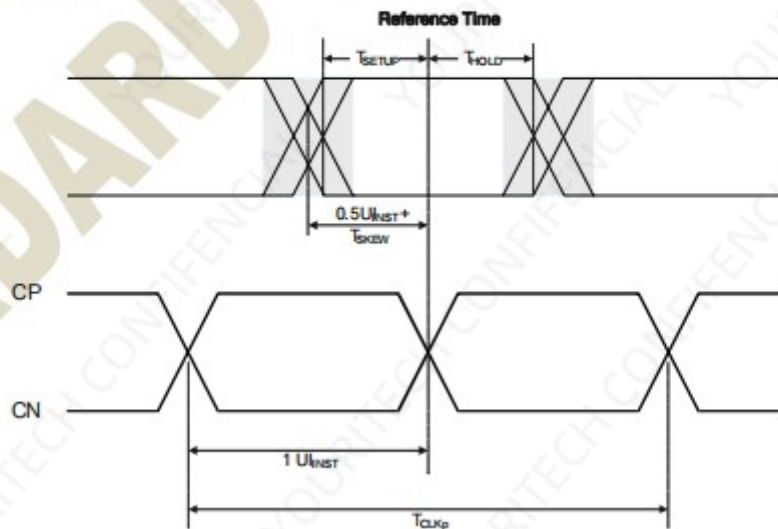
Table 11.11: Reverse HS Data Transmission Timing Parameters

The timing relationship of the DDR Clock differential signal to the Data differential signal is shown in Figure 8.13. Data is launched in a quadrature relationship to the clock such that the Clock signal edge may be used directly by the receiver to sample the received data.

The transmitter shall ensure that a rising edge of the DDR clock is sent during the first payload bit of a transmission burst such that the first payload bit can be sampled by the receiver on the rising clock edge, the second bit can be sampled on the falling edge, and all following bits can be sampled on alternating rising and falling edges.

All timing values are measured with respect to the actual observed crossing of the Clock differential signal. The effects due to variations in this level are included in the clock to data timing budget.

Receiver input offset and threshold effects shall be accounted as part of the receiver setup and hold parameters.



Low-Power Receiver (RX)

The low power receiver is an un-terminated, single-ended receiver circuit. The LP receiver is used to detect the Low-Power state on each pin. For high robustness, the LP receiver shall filter out noise pulses and RF interference. It is recommended the implementer optimize the LP receiver design for low power. The LP receiver shall reject any input glitch when the glitch is smaller than eSPIKE. The filter shall allow pulses wider than TMIN to propagate through the LP receiver. The Figure 13.4 shows Input Glitch Rejection of Low-Power RX. In addition, under tables list DC and AC characteristic for LP-RX.

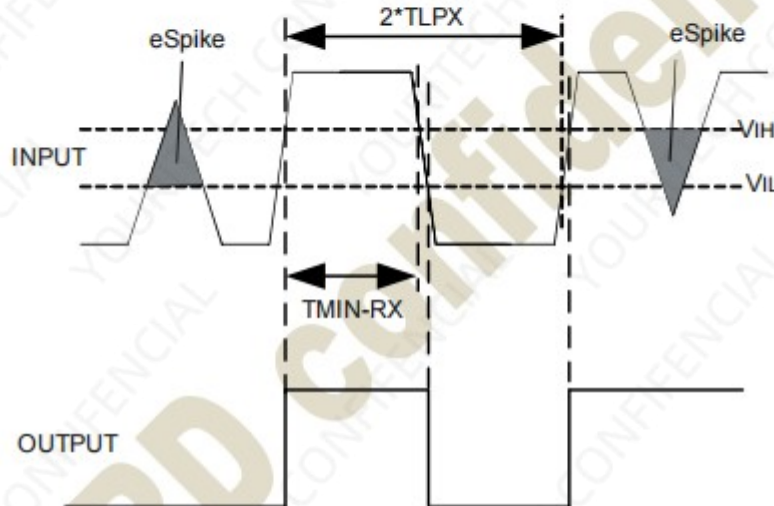


Figure 11.4: Input Glitch Rejections of Low-Power Receivers

Parameter	Description	Min.	Typ.	Max.	Unit	Note
V_{IH}	Logic 1 input threshold	880	-	-	mV	-
V_{IL}	Logic 0 input threshold, not in ULP state	-	-	550	mV	-

Table 11.6: LP-RX DC Specifications

Parameter	Description	Min.	Typ.	Max.	Unit	Note
e_{SPIKE}	Input pulse rejection	-	-	300	V.ps	1, 2, 3
T_{MIN}	Minimum pulse width response	20	-	-	ns	4
V_{INT}	Peak-to-peak interference voltage	-	-	200	mV	-
f_{INT}	Interference frequency	450	-	-	MHz	-

Note: (1) Time-voltage integration of a spike above V_{IL} when being in LP-0 state or below V_{IH} when being in LP-1 state
(2) An impulse less than this will not change the receiver state.
(3) In addition to the required glitch rejection, implementers shall ensure rejection of known RF-interferers.
(4) An input pulse greater than this shall toggle the output.

Burst Mode Data Transmission

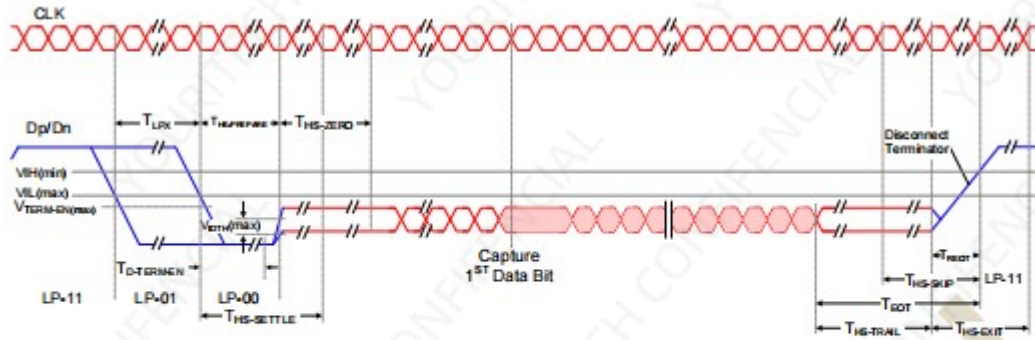


Figure 11.7: High-Speed Data Transmission in Bursts

Parameter	Description	Min	Typ	Max	UNIT
T_{LPX}	Transmitted length of any Low-Power state period	50	-	-	ns
$T_{HS-PREPARE}$	Time that the transmitter drives the Data Lane LP-00 Line state immediately before the HS-0 Line state starting the HS transmission	$40 + 4 \cdot UI$	-	$85 + 6 \cdot UI$	ns
$T_{HS-PREPARE} + T_{HS-ZERO}$	$T_{HS-PREPARE}$ + time that the transmitter drives the HS-0 state prior to transmitting the Sync sequence.	$145 + 10 \cdot UI$	-	-	ns
$T_{D-TERM-EN}$	Time for the Data Lane receiver to enable the HS line termination.	-	-	$35 + 4 \cdot UI$	ns
$T_{HS-SETTLE}$	Time interval during which the HS receiver shall ignore any Data Lane HS transitions.	$85 + 6 \cdot UI$	-	$145 + 10 \cdot UI$	ns
$T_{HS-TRAIL}$	Time that the transmitter drives the flipped differential state after last payload data bit of a HS transmission burst	$\max(n \cdot 8 \cdot UI, 60 + n \cdot 4 \cdot UI)$	-	-	ns
$T_{HS-EXIT}$	Time that the transmitter drives LP-11 following a HS burst.	100	-	-	ns

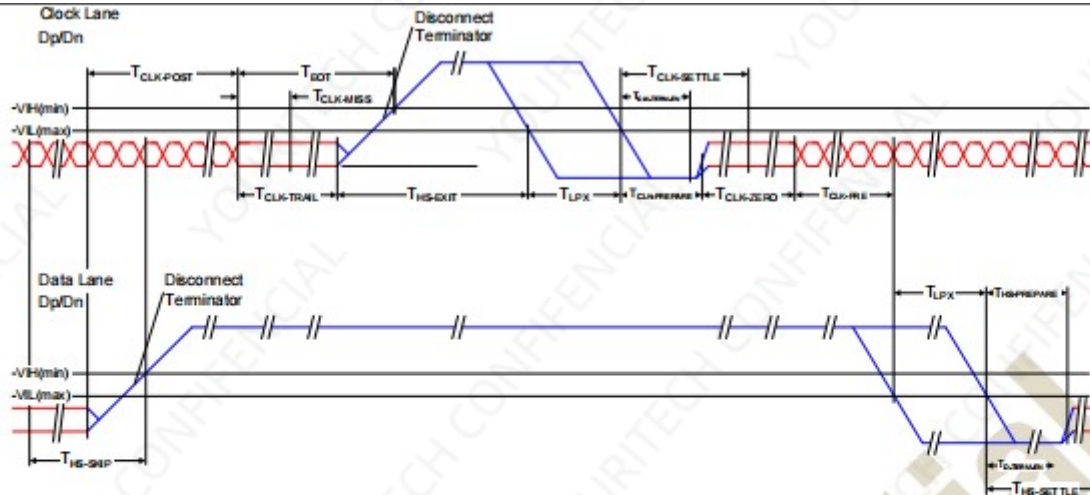


Figure 11.8: Switching the Clock Lane between Clock Transmission and Low-Power Mode

Parameter	Description	Min	Typ	Max	UNIT
$T_{CLK-POST}$	Time that the transmitter continues to send HS clock after the last associated Data Lane has transitioned to LP Mode.	$60 + 52 \cdot UI$	-	-	ns
$T_{CLK-PRE}$	Time that the HS clock shall be driven by the transmitter prior to any associated Data Lane beginning the transition from LP to HS mode.	$8 \cdot UI$	-	-	ns
$T_{CLK-PREPARE}$	Time that the transmitter drives the Clock Lane LP-00 Line state immediately before the HS-0 Line state starting the HS transmission.	38	-	95	ns
$T_{CLK-PREPARE} + T_{CLK-ZERO}$	$T_{CLK-PREPARE}$ + time that the transmitter drives the HS-0 state prior to starting the Clock.	300	-	-	ns
$T_{CLK-TERM-EN}$	Time for the Clock Lane receiver to enable the HS line termination.	-	-	38	ns
$T_{CLK-TRAIL}$	Time that the transmitter drives the HS-0 state after the last payload clock bit of a HS transmission burst.	60	-	-	ns
$T_{HS-EXIT}$	Time that the transmitter drives LP-11 following a HS burst.	100	-	-	ns

Reset input timings

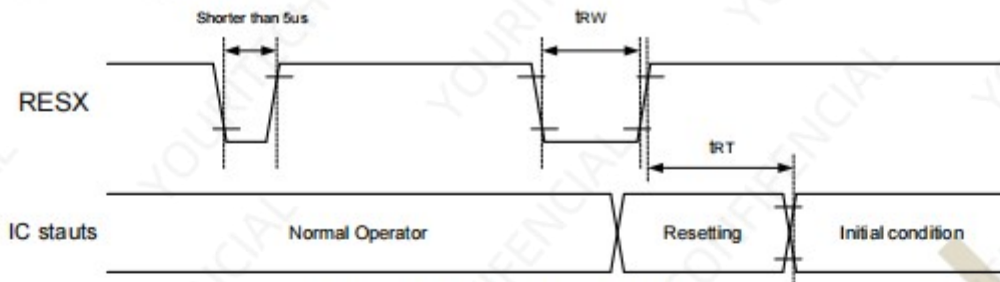


Figure 11.1: Reset input timings

Symbol	Parameter	Related pins	Min.	Max.	Unit
t_{RW}	Reset pulse width ⁽²⁾	RESX	10	-	μs
t_{RT}	Reset complete time ⁽³⁾	-	-	5 (Note 5)	ms
		-	-	120 (Note 6, 7)	ms

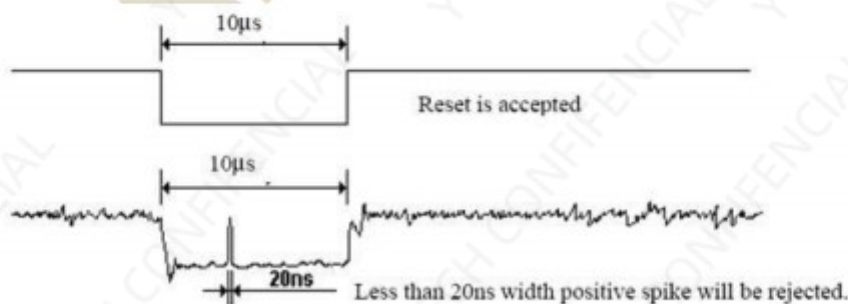
Note: (1) The reset complete time also required time for loading ID bytes from OTP to registers. This loading is done every time when there is HW reset cancel time (t_{RT}) within 5 ms after a rising edge of RESX.

(2) Spike due to an electrostatic discharge on RESX line does not cause irregular system reset according to the table below.

RESX Pulse	Action
Shorter than 5 μs	Reset Rejected
Longer than 10 μs	Reset
Between 5 μs and 10 μs	Reset Start

(3) During the resetting period, the display will be blanked (The display is entering blanking sequence, which maximum time is 120 ms, when Reset Starts in Sleep Out -mode. The display remains the blank state in Sleep In -mode) and then returns to Default condition for HW reset.

(4) Spike Rejection also applies during a valid reset pulse as shown below:



(5) When Reset is applied during Sleep In Mode.

(6) When Reset is applied during Sleep Out Mode.

(7) It is necessary to wait 5msec after releasing RESX before sending commands. Also Sleep Out command cannot be sent for 120msec.

(8) After Sleep Out Command, it is necessary to wait 120msec then send RESX.

7.Optical Characteristics

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit	Remark
Viewing Angle range	Horizontal	Θ_3	CR > 10	-	80	-	Deg.	Note 1
		Θ_9		-	80	-	Deg.	
	Vertical	Θ_{12}		-	80	-	Deg.	
		Θ_6		-	80	-	Deg.	
Luminance Contrast ratio		CR	$\Theta = 0^\circ$	1200	1500	-		Note 2
Transmittance		T(%)	$\Theta = 0^\circ$	3.87	4.3	-	%	Base on C light Note 3 With APF
White Chromaticity		x_w	$\Theta = 0^\circ$	0.263	0.293	0.323		Color Filter (with ITO) Based On C light Note 4
		y_w		0.299	0.329	0.359		
Reproduction of color	Red	x_R	$\Theta = 0^\circ$	0.635	0.665	0.695		
		y_R		0.289	0.319	0.349		
	Green	x_G		0.227	0.257	0.287		
		y_G		0.547	0.577	0.607		
	Blue	x_B		0.107	0.137	0.167		
		y_B		0.065	0.095	0.125		
Threshold Voltage		Vsat		3.7	3.9	4.1	V	Figure 3
		Vth		1.8	2.0	2.2	V	
Response Time (Rising + Falling)		T _{RT}	Ta= 25° C $\Theta = 0^\circ$	-	25	30	ms	Note 5

Notes : 1. Viewing angle is the angle at which the contrast ratio is greater than 10. The viewing angles are determined for the horizontal or 3, 9 o'clock direction and the vertical or 6, 12 o'clock direction with respect to the optical axis which is normal to the LCD surface (see Figure 4 shown in Appendix).

2. Contrast measurements shall be made at viewing angle of $\Theta = 0^\circ$ and at the center of the LCD surface. Luminance shall be measured with all pixels in the view field set first to white, then to the dark (black) state. (see Figure 4) Luminance Contrast Ratio (CR) is defined mathematically.

$$CR = \frac{\text{Luminance when displaying a white raster}}{\text{Luminance when displaying a black raster}}$$

3. Transmittance is the Value with Polarizer

4. The color chromaticity coordinates specified in Table 4 shall be calculated from the spectral data measured with all pixels first in red, green, blue and white. Measurements shall be made at the center of the panel. Measurement condition is C- light Source & Halogen Lampe

5. The electro-optical response time measurements shall be made as Figure 5 by switching the "data" input signal ON and OFF. The times needed for the transmittance to change from 10% to 90% is T_r , and 90% to 10% is T_f .

8. Reliability Test Item

No.	Test Item	Test Condition	Notes
1	High Temp. Storage	+80°C / 240H	1. Functional test isOK. Missing Segment,short, unclear segment non-display,display abnormally and liquid crystal leakare un-allowed. 2. No low temperature bubbles,end seal loose andfall, frame rainbow.
2	Low Temp. Storage	-30°C / 240H	
3	High Tempe. Operating	+70°C / 240H	
4	Low Tempe. Operating	-20°C / 240H	
5	High Temperature /Humidity storage	50+5°C x 90%RH / 48H	
6	Thermal and cold shock	Static state, -30°C (1 hour) ~60°C (1 hour) ~ -30°C (1 hour), packaging, 10 cycles	

9. Packing Method----TBD

- END -